

5W Ku-Band Power Amplifier 12.0-15.0 GHz

Features

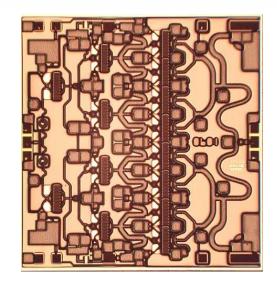
- 12.0-15.0 GHz Operation
- 5 Watt Saturated Output Power Level
- Variable Drain Voltage (4-10V) Operation
- Self-Aligned MSAG[®] MESFET Process

Description

The MAAPGM0016-DIE is a 3-stage 5 W power amplifier with on-chip bias networks. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate (MSAG[™]) Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG[™] process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



Primary Applications

- ♦ Point-to-Point Radio
- SatCom
- DBS

| Parameter | Symbol | Typical | Units |
|--------------------------|---------------------|-----------|-------|
| Bandwidth | f | 12.0-15.0 | GHz |
| Output Power | P _{OUT} 37 | | dBm |
| Power Added Efficiency | PAE | 24 | % |
| 1-dB Compression Point | P1dB | 36 | dBm |
| Small Signal Gain | Gn | 20 | dB |
| Input VSWR | VSWR | 3:1 | |
| Gate Current | I _{GG} | <2 | mA |
| Drain Current | I _{DD} | <3.5 | А |
| 2 nd Harmonic | 2f | -40 | dBc |
| 3 rd Harmonic | 3f | -75 | dBc |

Electrical Characteristics: $T_B = 40^{\circ}C^1$, $Z_0 = 50 \Omega$, $V_{DD} = 8V$, $I_{DQ} = 2.4 A^2$, $P_{in} = 21 \text{ dBm}$, $R_G = 25 \Omega$

1. T_B = MMIC Base Temperature

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2. Adjust V_{gg} between -2.5 and -1.2V to achieve specified Idq.

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Visit www.macom.com for additional data sheets and product information.



MAAPGM0016-DIE Rev A Preliminary Datasheet

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Maximum Ratings ³

| Parameter | Symbol | Absolute Maximum | Units | |
|---------------------------------------|-------------------|------------------|-------|--|
| Input Power | P _{IN} | 28.0 | dBm | |
| Drain Supply Voltage | V _{DD} | +12.0 | V | |
| Gate Supply Voltage | V _{GG} | -3.0 | V | |
| Quiescent Drain Current (No RF) | I _{DQ} | 2.5 | A | |
| Quiescent DC Power Dissipated (No RF) | P _{DISS} | 20.3 | W | |
| Junction Temperature | TJ | 170 | °C | |
| Storage Temperature | T _{STG} | -55 to +150 | °C | |

3. Operation beyond these limits may result in permanent damage to the part.

Recommended Operating Conditions⁴

| Characteristic | Symbol | Min | Тур | Max | Unit |
|-----------------------|-----------------|------|------|--------|------|
| Drain Voltage | V _{DD} | 4.0 | 8.0 | 10.0 | V |
| Gate Voltage | V_{GG} | -2.5 | -2.0 | -1.2 | V |
| Input Power | P _{IN} | | 6.0 | 25.0 | dBm |
| Thermal Resistance | Θ _{JC} | | 3.9 | | °C/W |
| MMIC Base Temperature | Τ _B | | | Note 5 | °C |

4. Operation outside of these ranges may reduce product reliability.

5. MMIC Base Temperature = $170^{\circ}C - \Theta_{JC} V_{DD} * I_{DQ}$

Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply V_{GG} = -2.7 V, V_{DD} = 0 V.
- 2. Ramp V_{DD} to desired voltage, typically 8.0 V.
- 3. Adjust V_{GG} to set I_{DQ} , (approximately @ -2 V).
- 4. Set RF input.
- 5. Power down sequence in reverse. Turn V_{GG} off last.



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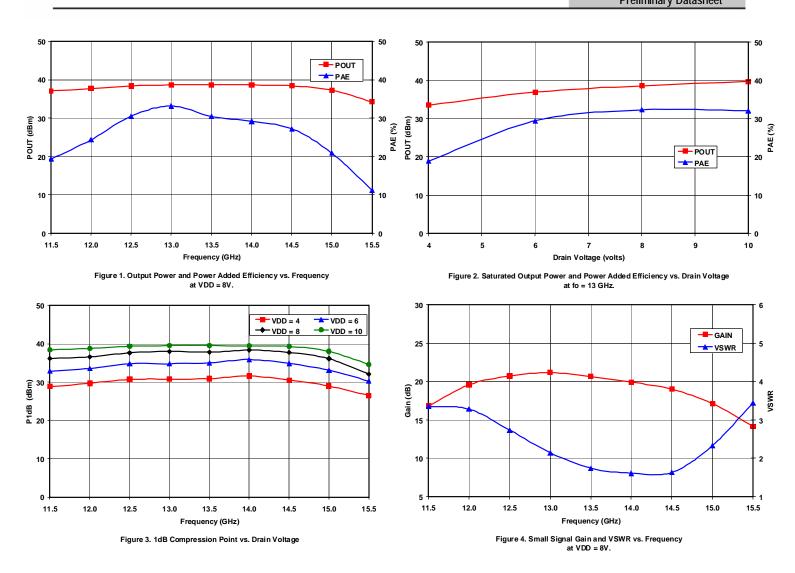
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Mechanical Information

Chip Size: 4.206 x 4.404 x 0.075 mm (166 x 173 x 3 mils)

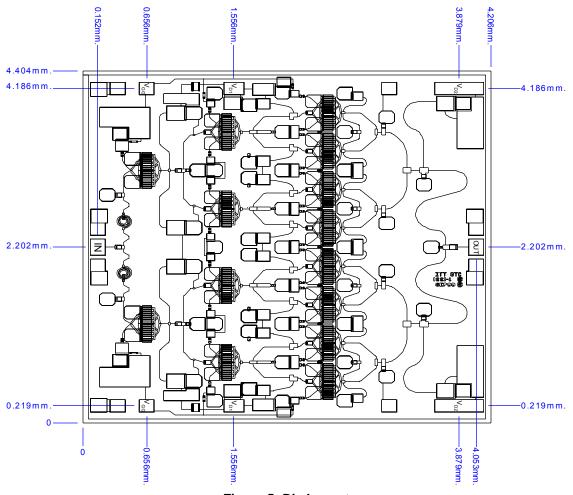


Figure 5. Die Layout

Bond Pad Dimensions

| Pad | Size (μm) | Size (mils) |
|----------------------------------|-----------|-------------|
| RF In and Out | 100 x 200 | 4 x 8 |
| DC Drain Supply Voltage V_{D1} | 200 x 150 | 8 x 6 |
| DC Drain Supply Voltage V_{D2} | 500 x 150 | 20 x 6 |
| DC Gate Supply Voltage V_{GG} | 150 x 150 | 6 x 6 |

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Rev A

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Assembly and Bonding Diagram

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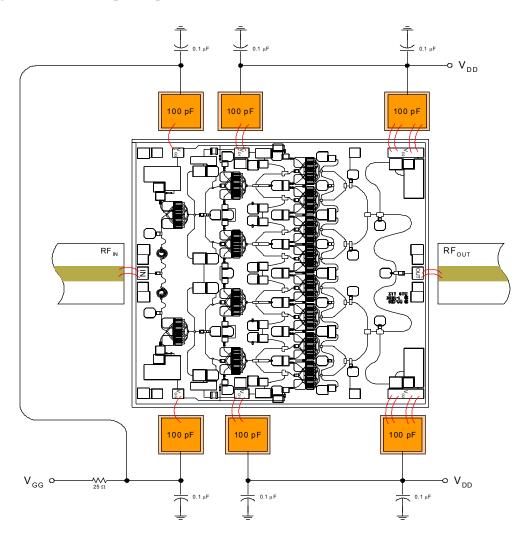


Figure 6. Die Layout

Assembly Instructions:

Die attach: Use AuSn (80/20) 1 mil. preform solder. Limit time @ 300 °C to less than 5 minutes.

Wirebonding: Bond @ 160 °C using standard ball or thermal compression wedge bond techniques. For DC pad connections, use either ball or wedge bonds. For best RF performance, use wedge bonds of shortest length, although ball bonds are also acceptable.

Biasing Note: Must apply negative bias to V_{GG} before applying positive bias to V_{DD} to prevent damage to amplifier.

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